

## SILICON BRIDGE RECTIFIER

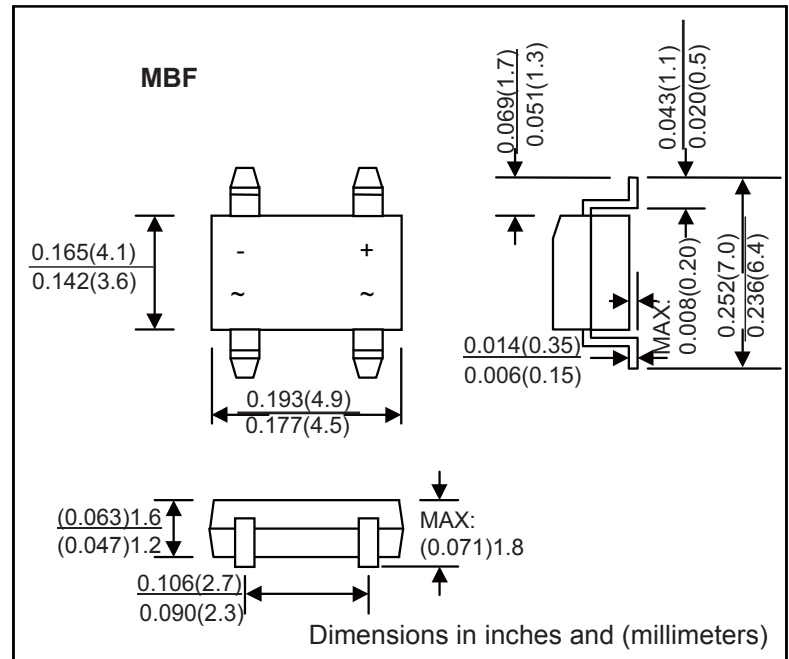
REVERSE VOLTAGE : 50 --- 1000 V CURRENT: 0.5 A

### Features

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Surge Current Capability
- Designed for Surface Mount Application
- Plastic Material – UL Flammability 94V-0

### Mechanical Data

- Case: MB-F, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-MIL-STSTD-D-202, 202, MetMethodhod 202088
- Polarity: As Marked on Case
- Weight: 0.134 grams (approx.)
- Monting Position: Any
- Marking:Type Number



## MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

Characteristic	Symbo	MB05F	MB1F	MB2F	MB4F	MB6F	MB8F	MB10F	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Working Peak Reverse Voltage	$V_{RWM}$								
DC Blocking Voltage	$V_R$								
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) @ $T_A = 40^\circ\text{C}$	$I_o$	0.5							A
Average Rectified Output Current (Note 2) @ $T_A = 40^\circ\text{C}$		0.8							
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	30							A
$I^2t$ Rating for Fusing ( $t < 8.3\text{ms}$ )	$I^2t$	5.0							$\text{A}^2\text{s}$
Forward Voltage per element @ $I_F = 0.5\text{A}$	$V_{FM}$	1.0							V
Peak Reverse Current @ $T_A = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_A = 125^\circ\text{C}$	$I_{RM}$	5.0 500							$\mu\text{A}$
Typical Junction Capacitance per leg (Note 3)	$C_j$	13							pF
Typical Thermal Resistance per leg (Note 1)	$R_{\theta JA}$ $R_{\theta JL}$	60 16							$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_j, T_{STG}$	-55 to +150							$^\circ\text{C}$

- Note: 1. Mounted on glass epoxy PC board with  $1.3\text{mm}^2$  solder pad.  
 2. Mounted on aluminum substrate PC board with  $1.3\text{mm}^2$  solder pad.  
 3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

# RATINGS AND CHARACTERISTIC CURVES

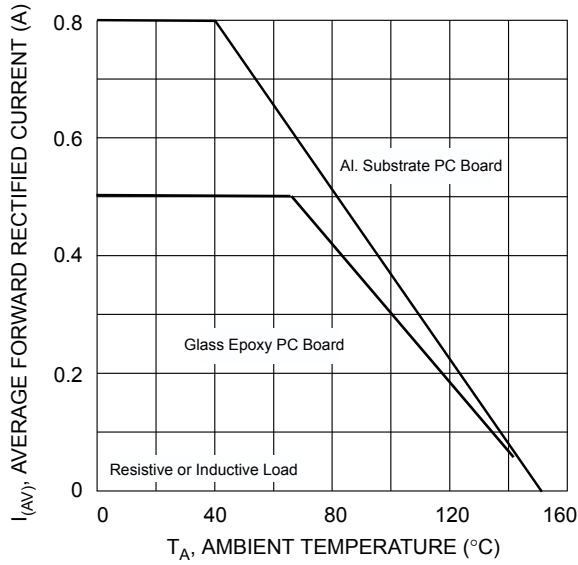


Fig. 1 Output Current Derating Curve

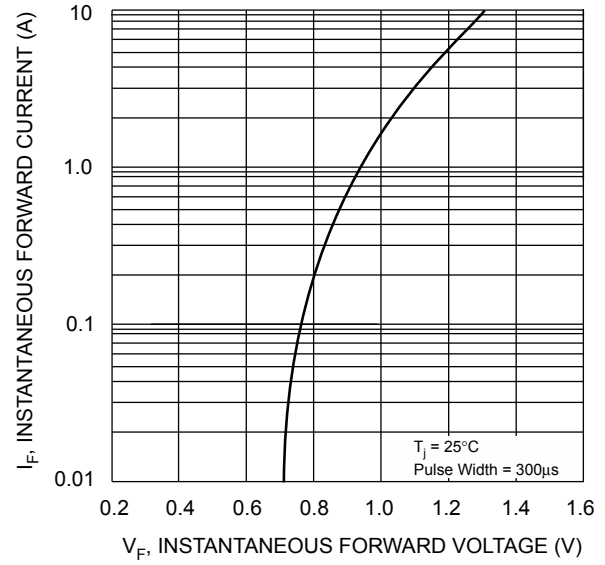


Fig. 2 Typical Forward Characteristics (per leg)

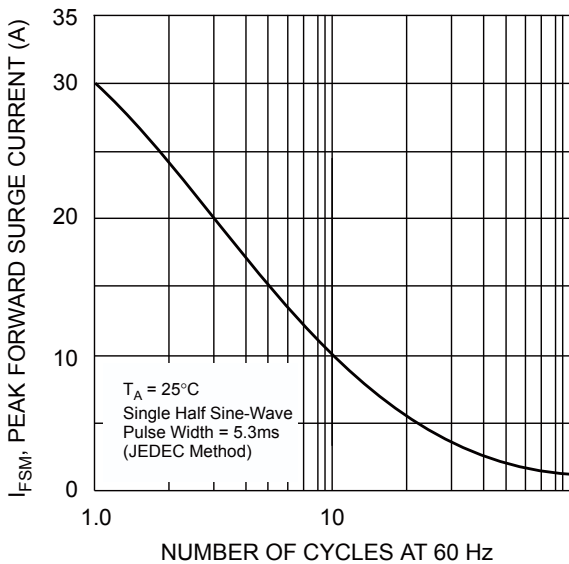


Fig. 3 Maximum Peak Forward Surge Current (per leg)

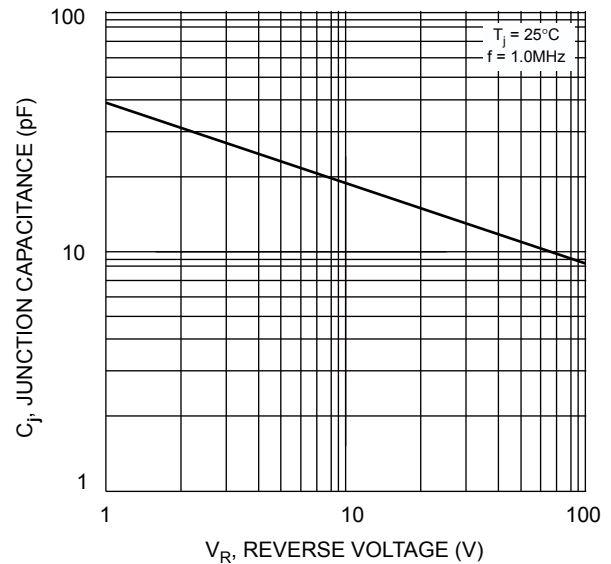


Fig. 4 Typical Junction Capacitance

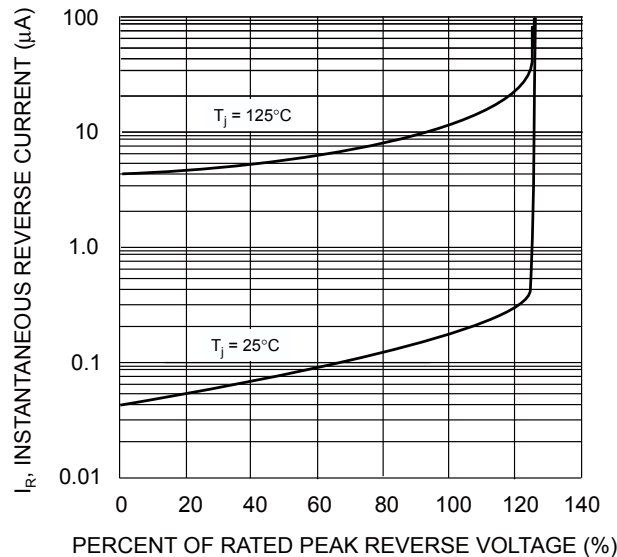


Fig. 5 Typical Reverse Characteristics (per element)